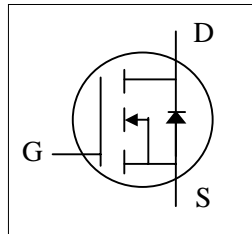




- ▼ Ease of Paralleling
- ▼ Fast Switching Characteristic
- ▼ Simple Drive Requirement

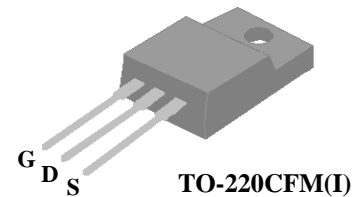


$BV_{DSS}$	500V
$R_{DS(ON)}$	0.85 $\Omega$
$I_D$	8A

## Description

APEC MOSFET provide the power designer with the best combination of fast switching , lower on-resistance and reasonable

The TO-220CFM isolation package is widely preferred for commercial-industrial through hole applications.



## Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	500	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D@T_C=25^\circ C$	Continuous Drain Current, $V_{GS}$ @ 10V	8	A
$I_D@T_C=100^\circ C$	Continuous Drain Current, $V_{GS}$ @ 10V	5.1	A
$I_{DM}$	Pulsed Drain Current <sup>1</sup>	32	A
$P_D@T_C=25^\circ C$	Total Power Dissipation	35	W
$E_{AS}$	Single Pulse Avalanche Energy <sup>2</sup>	320	mJ
$I_{AR}$	Avalanche Current	8	A
$T_{STG}$	Storage Temperature Range	-55 to 150	$^\circ C$
$T_J$	Operating Junction Temperature Range	-55 to 150	$^\circ C$

## Thermal Data

Symbol	Parameter	Value	Unit
Rthj-c	Maximum Thermal Resistance, Junction-case	3.6	$^\circ C/W$
Rthj-a	Maximum Thermal Resistance, Junction-ambient	65	$^\circ C/W$



**Electrical Characteristics @ $T_j=25^{\circ}\text{C}$ (unless otherwise specified)**

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=1mA$	500	-	-	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance <sup>3</sup>	$V_{GS}=10V, I_D=4.8A$	-	-	0.85	$\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	2	-	4	V
$g_{fs}$	Forward Transconductance	$V_{DS}=10V, I_D=4.8A$	-	4.2	-	S
$I_{DSS}$	Drain-Source Leakage Current ( $T_j=25^{\circ}\text{C}$ )	$V_{DS}=500V, V_{GS}=0V$	-	-	25	$\mu A$
	Drain-Source Leakage Current ( $T_j=125^{\circ}\text{C}$ )	$V_{DS}=400V, V_{GS}=0V$	-	-	250	$\mu A$
$I_{GSS}$	Gate-Source Leakage	$V_{GS}=\pm 20V$	-	-	$\pm 100$	nA
$Q_g$	Total Gate Charge <sup>3</sup>	$I_D=8A$	-	45	72	nC
$Q_{gs}$	Gate-Source Charge	$V_{DS}=400V$	-	7	-	nC
$Q_{gd}$	Gate-Drain ("Miller") Charge	$V_{GS}=10V$	-	25	-	nC
$t_{d(on)}$	Turn-on Delay Time <sup>3</sup>	$V_{DD}=250V$	-	12	-	ns
$t_r$	Rise Time	$I_D=8A$	-	31	-	ns
$t_{d(off)}$	Turn-off Delay Time	$R_G=9.1\Omega, V_{GS}=10V$	-	48	-	ns
$t_f$	Fall Time	$R_D=31\Omega$	-	33	-	ns
$C_{iss}$	Input Capacitance	$V_{GS}=0V$	-	1250	2000	pF
$C_{oss}$	Output Capacitance	$V_{DS}=25V$	-	270	-	pF
$C_{rss}$	Reverse Transfer Capacitance	$f=1.0MHz$	-	85	-	pF
$R_g$	Gate Resistance	$f=1.0MHz$	-	1.6	2.4	$\Omega$

**Source-Drain Diode**

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$V_{SD}$	Forward On Voltage <sup>3</sup>	$T_j=25^{\circ}\text{C}, I_S=8A, V_{GS}=0V$	-	-	1.5	V
$t_{rr}$	Reverse Recovery Time <sup>3</sup>	$I_S=8A, V_{GS}=0V,$	-	515	-	ns
$Q_{rr}$	Reverse Recovery Charge	$dI/dt=100A/\mu s$	-	8.6	-	$\mu C$

**Notes:**

- 1.Pulse width limited by Max. junction temperature.
- 2.Starting  $T_j=25^{\circ}\text{C}$  ,  $V_{DD}=50V$  ,  $L=10mH$  ,  $R_G=25\Omega$
- 3.Pulse test

THIS PRODUCT IS AN ELECTROSTATIC SENSITIVE, PLEASE HANDLE WITH CAUTION.

THIS PRODUCT HAS BEEN QUALIFIED FOR CONSUMER MARKET. APPLICATIONS OR USES AS CRITERIAL COMPONENT IN LIFE SUPPORT DEVICE OR SYSTEM ARE NOT AUTHORIZED.

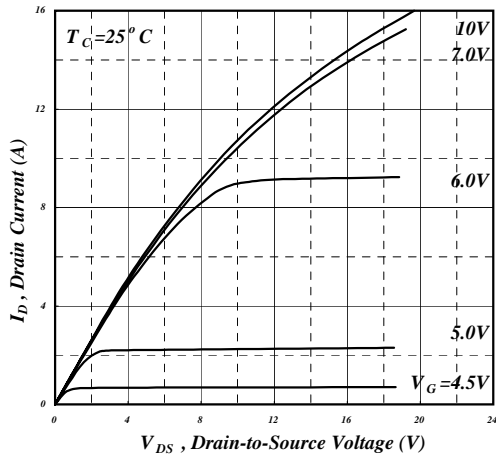


Fig 1. Typical Output Characteristics

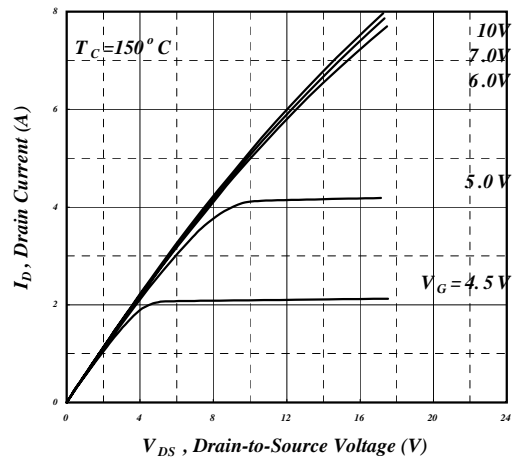


Fig 2. Typical Output Characteristics

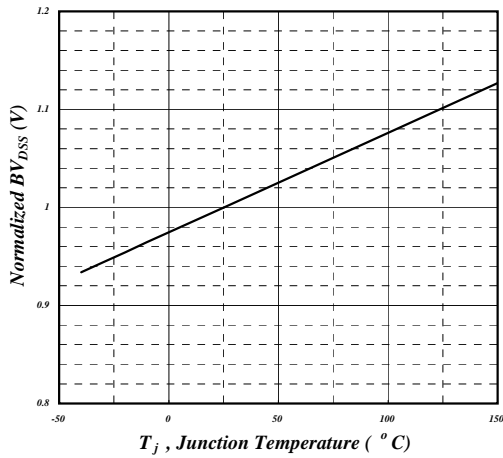


Fig 3. Normalized  $BV_{DSS}$  v.s. Junction Temperature

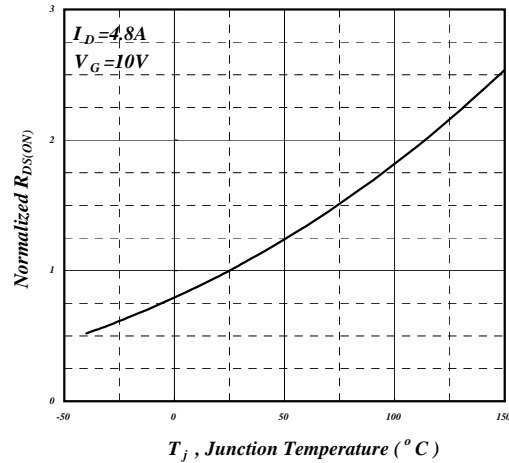


Fig 4. Normalized On-Resistance v.s. Junction Temperature

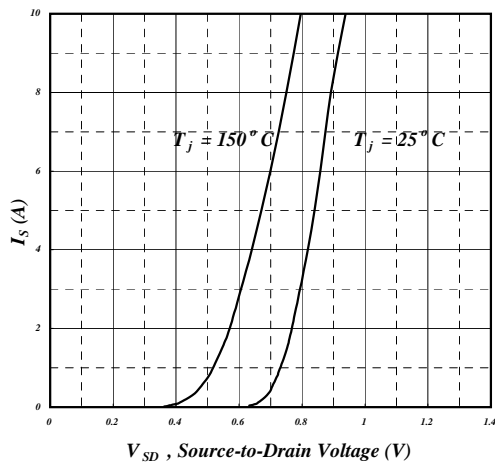


Fig 5. Forward Characteristic of Reverse Diode

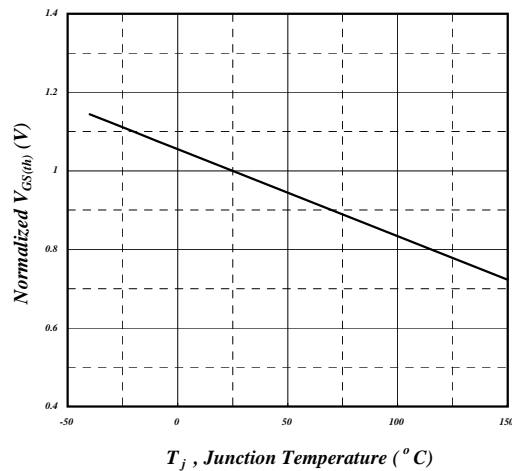


Fig 6. Gate Threshold Voltage v.s. Junction Temperature

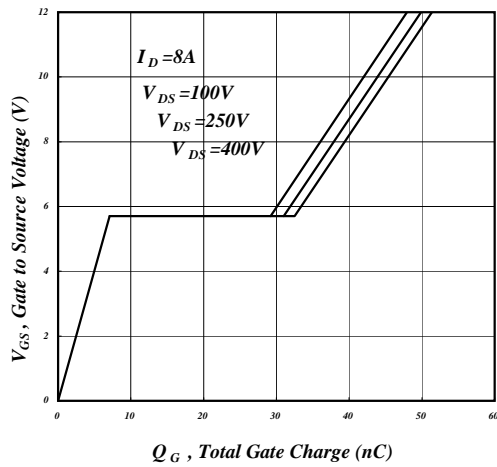


Fig 7. Gate Charge Characteristics

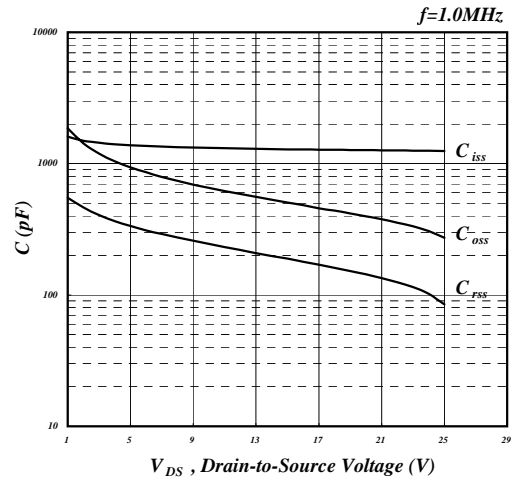


Fig 8. Typical Capacitance Characteristics

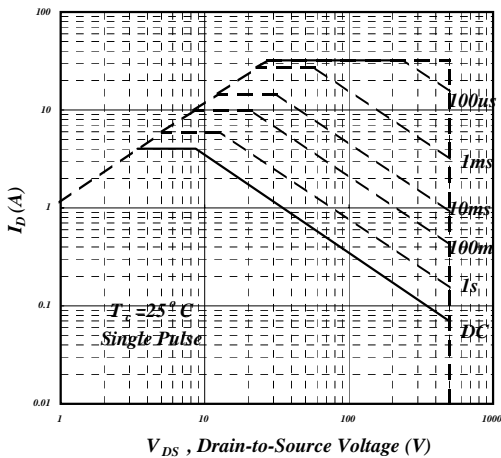


Fig 9. Maximum Safe Operating Area

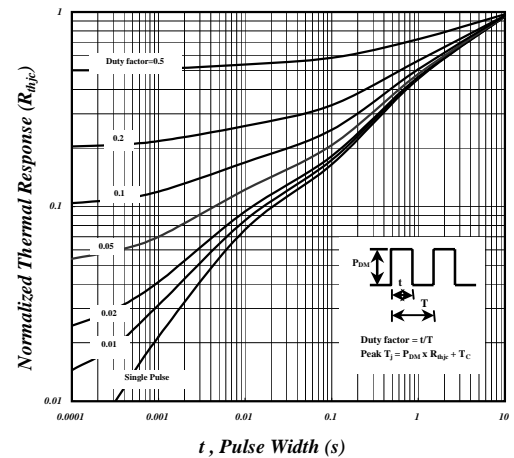


Fig 10. Effective Transient Thermal Impedance

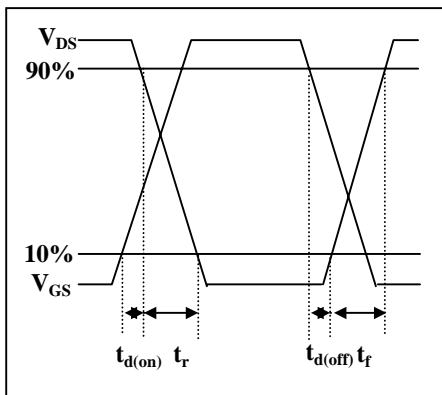


Fig 11. Switching Time Waveform

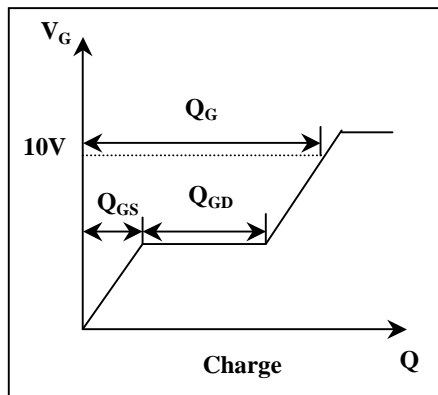
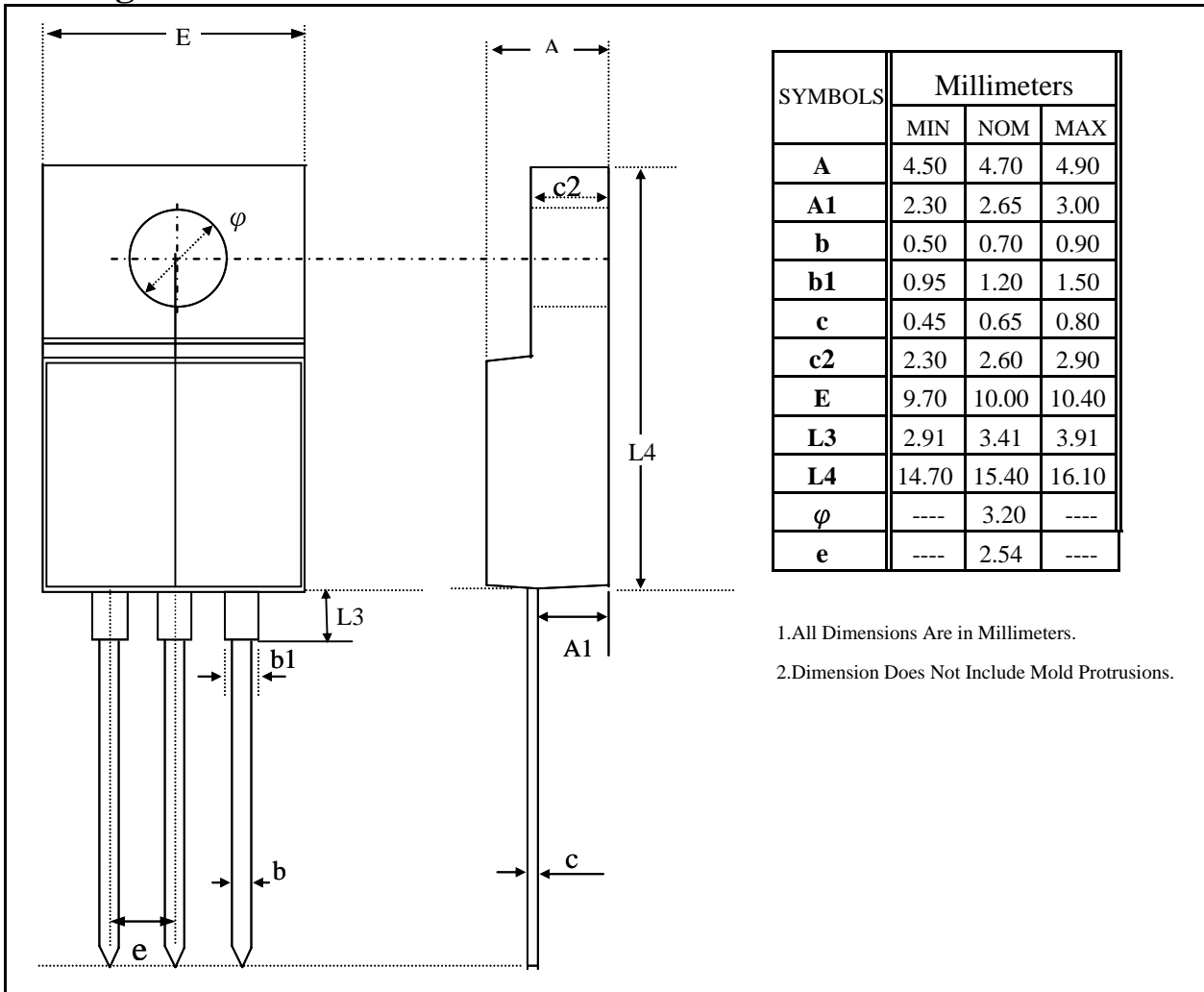


Fig 12. Gate Charge Waveform



### Package Outline : TO-220CFM



### Part Marking Information & Packing : TO-220CFM

